

Product Summary

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D $T_A = +25^\circ C$
300V	4Ω @ $V_{GS} = 10V$	0.25A
	4Ω @ $V_{GS} = 4.5V$	0.25A

Description and Applications

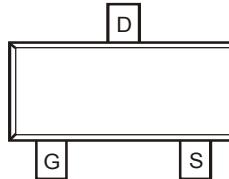
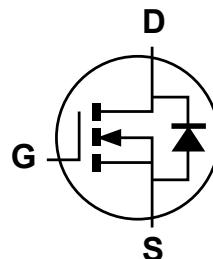
This new generation MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Description and Applications

- DC-DC Converters
- Power management functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc



Top View


 Top View
 Pin Configuration


Equivalent Circuit

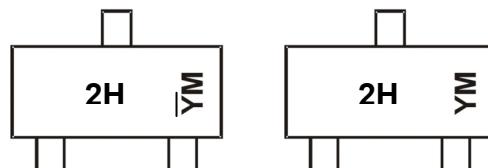
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN30H4D0L-7	SOT23	3,000/Tape & Reel
DMN30H4D0L-13	SOT23	10,000/Tape & Reel

Notes:

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



2H = Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)

YM = Date Code Marking for CAT (Chengdu Assembly/ Test site)

Y or YM = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Date Code Key

Year	2013	2014	2015	2016	2017	2018	2019					
Code	A	B	C	D	E	F	G					
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	300	V
Gate-Source Voltage			V_{GSS}	± 20	V
Continuous Drain Current (Note 6) $V_{GS} = 10\text{V}$	Steady State	$T_A = +25^\circ\text{C}$ $T_A = +70^\circ\text{C}$	I_D	0.25 0.20	A
Pulsed Drain Current (10 μs pulse, duty cycle $\leq 1\%$)			I_{DM}	2	A
Maximum Body Diode Continuous Current (Note 6)			I_S	0.8	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation	(Note 5)	P_D	0.31	W
	(Note 6)		0.47	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	377	°C/W
	(Note 6)		255	
Thermal Resistance, Junction to Case	(Note 6)	$R_{\theta JC}$	81	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to 150	°C

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	300	—	—	V	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	1.0	μA	$V_{DS} = 240\text{V}, V_{GS} = 0\text{V}$
Gate-Body Leakage	I_{GSS}	—	—	± 100	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(\text{th})}$	1	—	3	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(\text{ON})}$	—	2.1	4	Ω	$V_{GS} = 10\text{V}, I_D = 0.3\text{A}$
		—	2.1	4		$V_{GS} = 4.5\text{V}, I_D = 0.2\text{A}$
		—	3.8	6		$V_{GS} = 2.7\text{V}, I_D = 0.1\text{A}$
Diode Forward Voltage	V_{SD}	—	0.7	1.2	V	$V_{GS} = 0\text{V}, I_S = 0.3\text{A}$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C_{iss}	—	187.3	—	pF	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Output Capacitance	C_{oss}	—	11.7	—		
Reverse Transfer Capacitance	C_{rss}	—	8.7	—		
Total Gate Charge	Q_g	—	7.6	—	nC	$V_{DS} = 192\text{V}, V_{GS} = 10\text{V}, I_D = 0.5\text{A}$
Gate-Source Charge	Q_{gs}	—	0.5	—		
Gate-Drain Charge	Q_{gd}	—	3.3	—		
Turn-On Delay Time	$t_{D(\text{on})}$	—	4.9	—	nS	$V_{DS} = 60\text{V}, R_L = 200\Omega$ $V_{GS} = 10\text{V}, R_G = 25\Omega$
Turn-On Rise Time	t_r	—	4.7	—		
Turn-Off Delay Time	$t_{D(\text{off})}$	—	25.8	—		
Turn-Off Fall Time	t_f	—	17.5	—		

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

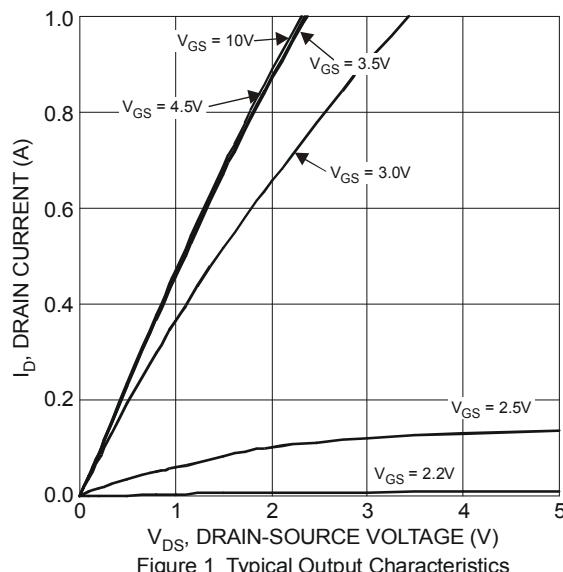


Figure 1 Typical Output Characteristics

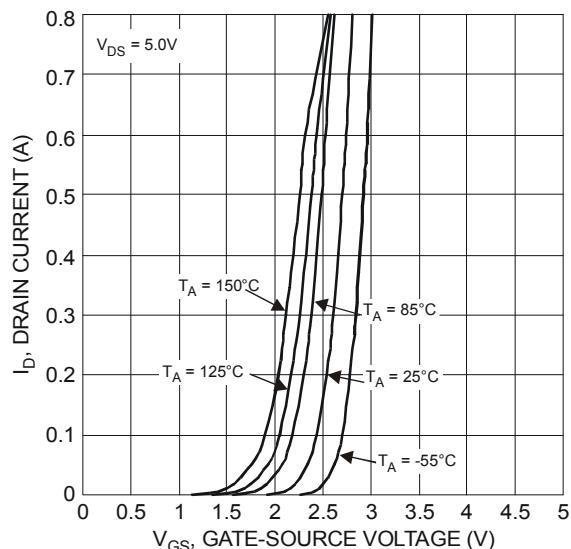


Figure 2 Typical Transfer Characteristics

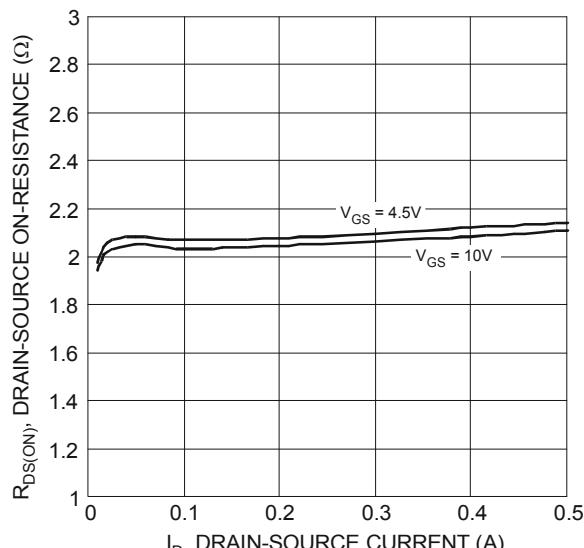


Figure 3 Typical On-Resistance vs.
Drain Current and Gate Voltage

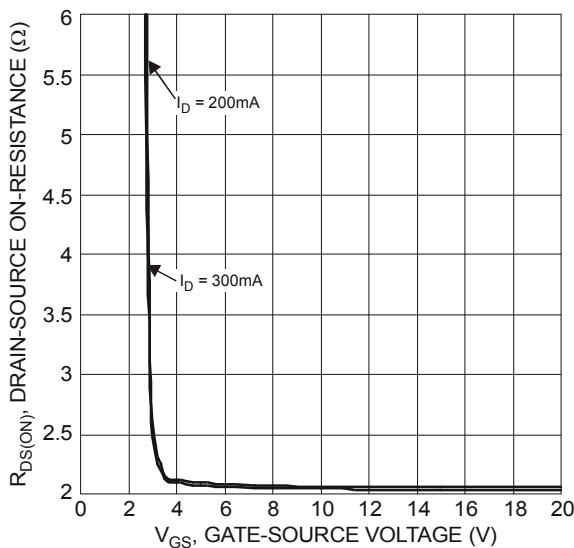


Figure 4 Typical Transfer Characteristics

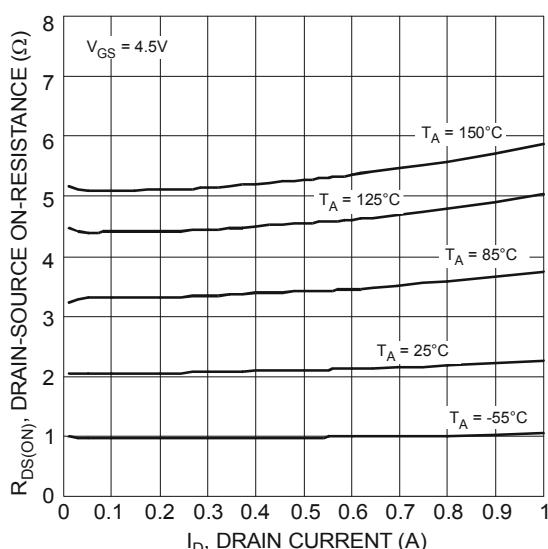


Figure 5 Typical On-Resistance vs.
Drain Current and Temperature

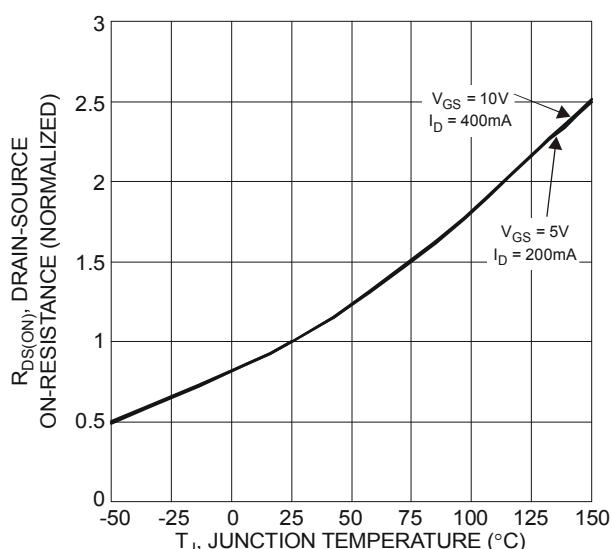
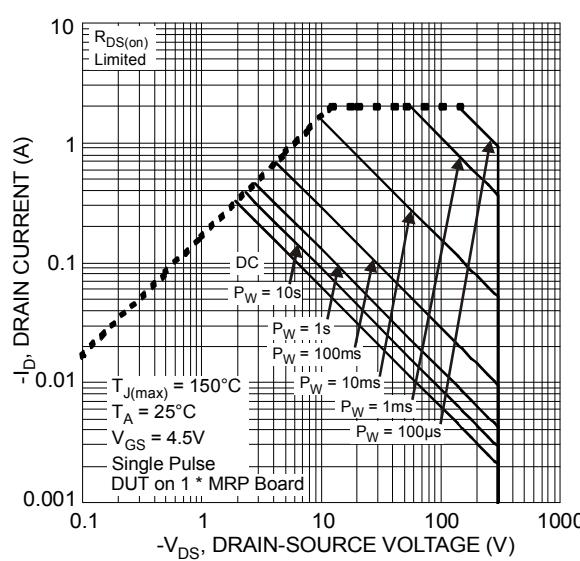
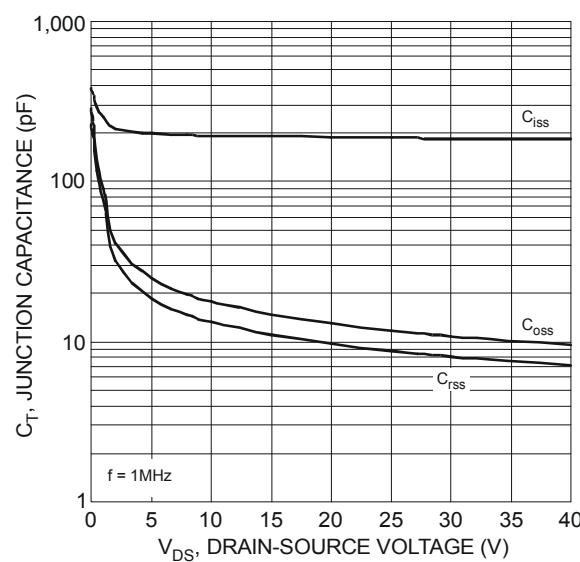
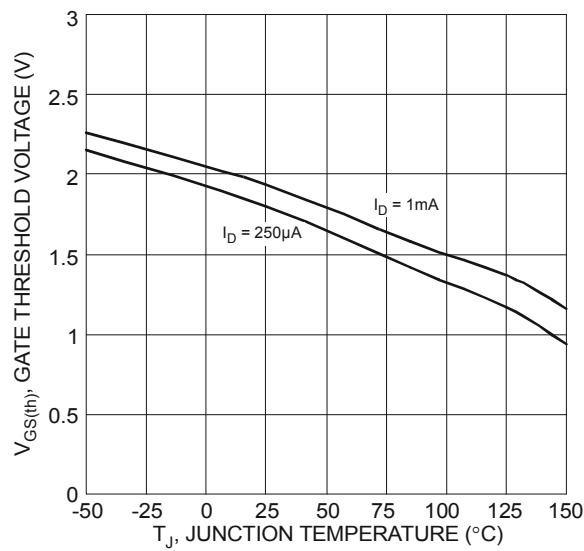
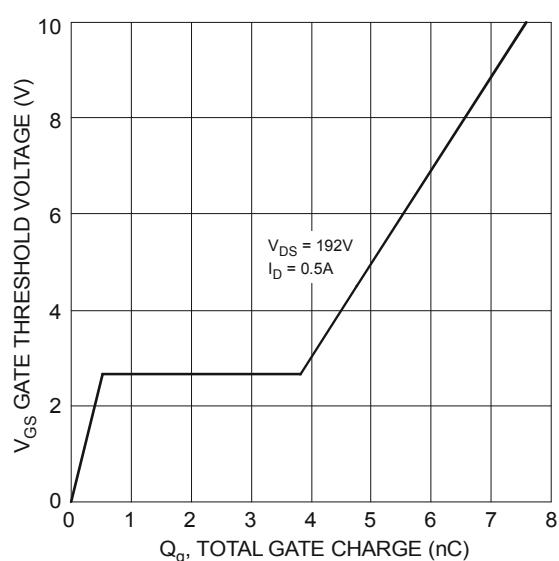
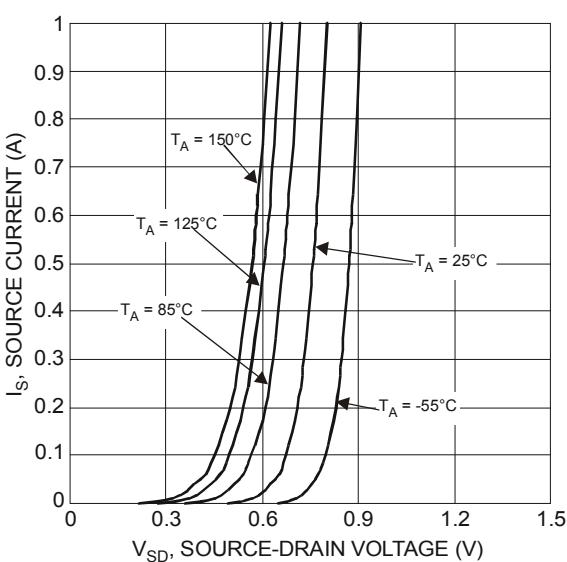
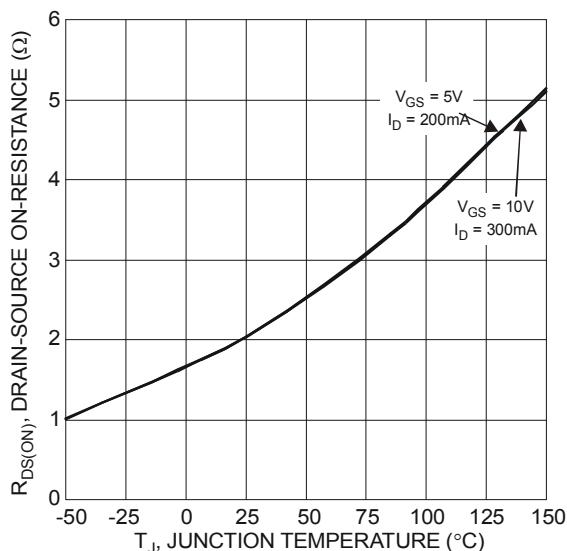
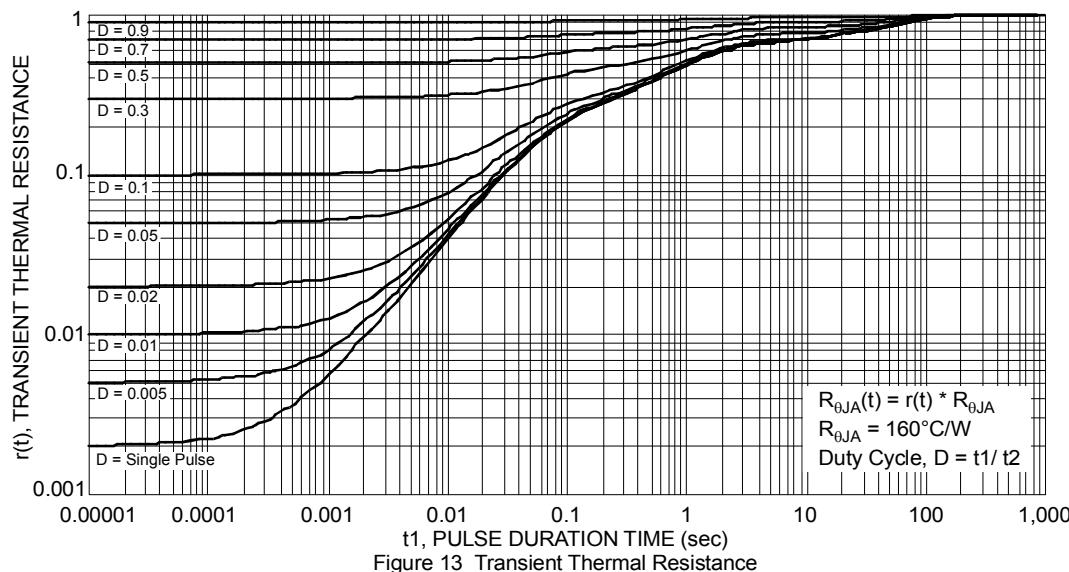


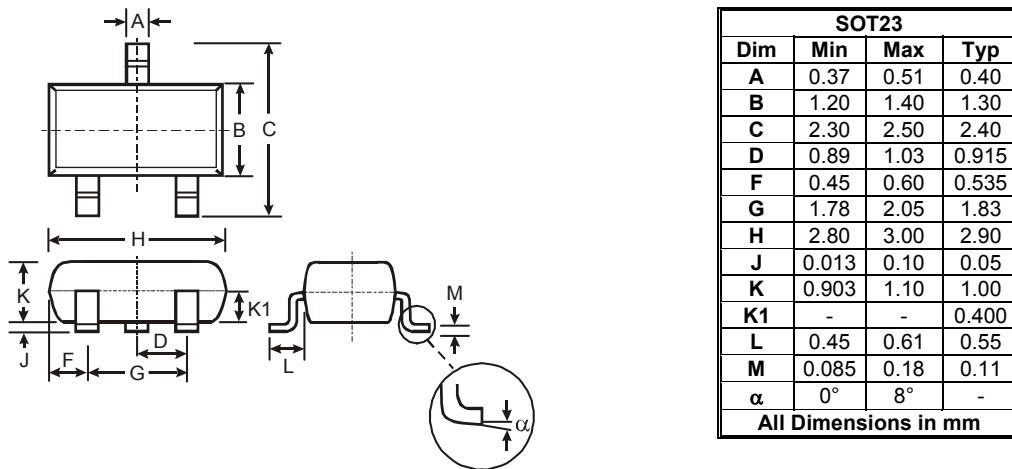
Figure 6 On-Resistance Variation with Temperature





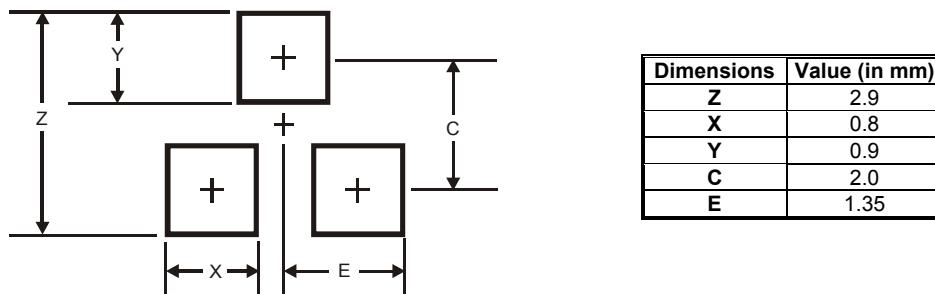
Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for latest version.



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